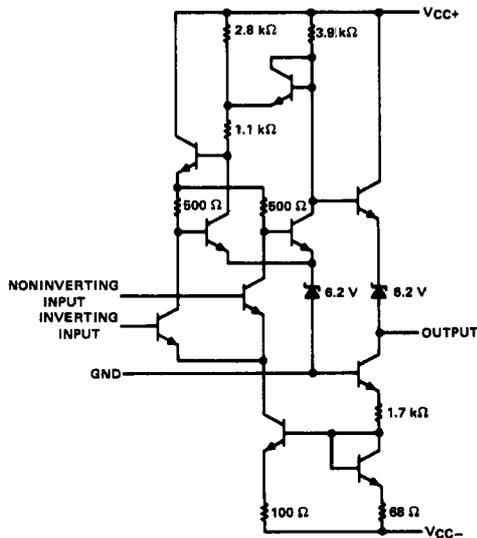


- Fast Response Times
- Low Offset Characteristics
- Output Compatible with Most TTL Circuits

description

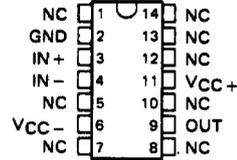
The TL710 is a monolithic high-speed comparator having differential inputs and a low-impedance output. Component matching, inherent in silicon integrated circuit fabrication techniques, produces a comparator with a low-drift and low-offset characteristics. These circuits are especially useful for applications requiring an amplitude discriminator, memory sense amplifier, or a high-speed voltage comparator. The TL710M is characterized for operation over the full military temperature range of -55°C to 125°C ; the TL710C is characterized for operation from 0°C to 70°C .

schematic

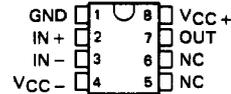


Component values shown are nominal.

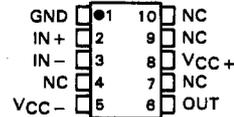
**J OR N DUAL-IN-LINE PACKAGE
(TOP VIEW)**



**JG OR P DUAL-IN-LINE PACKAGE
(TOP VIEW)**

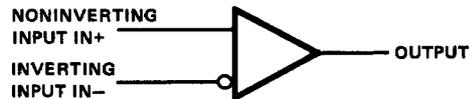


**U FLAT PACKAGE
(TOP VIEW)**



NC—No internal connection

symbol



TYPES TL710M, TL710C DIFFERENTIAL COMPARATORS

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

	TL710M	TL710C	UNIT
Supply voltage V_{CC+} (see Note 1)	14	14	V
Supply voltage V_{CC-} (see Note 1)	-7	-7	V
Differential input voltage (see Note 2)	± 5	± 5	V
Input voltage (either input, see Note 1)	± 7	± 7	V
Peak output current ($t_w \leq 1$ s)	10	10	mA
Continuous total power dissipation at (or below) 70°C free-air temperature (see Note 3)	300	300	mW
Operating free-air temperature range	-55 to 125	0 to 70	°C
Storage temperature range	-65 to 150	-65 to 150	°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J, JG or U package	300	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	N or P package	260	°C

- NOTES: 1. All voltage values, except differential voltages, are with respect to the network ground terminal.
2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
3. For operation of the TL710M above 70°C free-air temperature, refer to Dissipation Derating Curves, Section 2. In the J and JG packages, TL710M chips are alloy-mounted; TL710C chips are glass-mounted.

electrical characteristics at specified free-air temperature, $V_{CC+} = 12$ V, $V_{CC-} = -6$ V

PARAMETER	TEST CONDITIONS [†]	TL710M		TL710C		UNIT			
		MIN	TYP	MAX	MIN		TYP	MAX	
V_{IO} Input offset voltage	$R_S \leq 200 \Omega$, See Note 4	25°C	2	5	2	7.5	mV		
		Full range	6		10				
α_{VIO} Average temperature coefficient of input offset voltage	$R_S \leq 200 \Omega$, See Note 4	Full range	5		7.5		$\mu\text{V}/^\circ\text{C}$		
I_{IO} Input offset current	See Note 4	25°C	1	10	1	15	μA		
		Full range	20		25				
I_{IB} Input bias current	See Note 4	25°C	25	75	25	100	μA		
		Full range	150		150				
V_{ICR} Common-mode input voltage range	$V_{CC} = -7$ V	25°C	± 5		± 5		V		
V_{ID} Differential input voltage range		25°C	± 5		± 5		V		
A_{VD} Large-signal differential voltage amplification	No load, See Note 4	25°C	750	1500	700	1500	V/V		
		Full range	500		500				
V_{OH} High-level output voltage	$V_{ID} = 15$ mV, $I_{OH} = -0.5$ mA	25°C	2.5	3.2	4	2.5	3.2	4	V
V_{OL} Low-level output voltage	$V_{ID} = -15$ mV, $I_{OL} = 0$	25°C	-1	-0.5	0 [‡]	-1	-0.5	0 [‡]	V
I_{OL} Low-level output current	$V_{ID} = -15$ mV, $V_O = 0$	25°C	1.6		2.5		μA		
r_o Output resistance	$V_O = 1.4$ V	25°C	200		200		Ω		
CMRR Common-mode rejection ratio	$R_S \leq 200 \Omega$	25°C	70	90	65	90	dB		
I_{CC+} Supply current from V_{CC+}	$V_{ID} = -5$ V to 5 V (-10 mV for typ)	25°C	5.4		10.1		mA		
I_{CC-} Supply current from V_{CC-}		25°C	-3.8		-8.9		mA		
P_D Total power dissipation		No load	25°C	88	175	88		mW	

NOTE 4: These characteristics are verified by measurements at the following temperatures and output voltage levels: for TL710M, $V_O = 1.8$ V at $T_A = -55^\circ\text{C}$, $V_O = 1.4$ V at $T_A = 25^\circ\text{C}$, and $V_O = 1$ V at $T_A = 125^\circ\text{C}$; for TL710C, $V_O = 1.5$ V at $T_A = 0^\circ\text{C}$, $V_O = 1.4$ V at $T_A = 25^\circ\text{C}$, and $V_O = 1.2$ V at $T_A = 70^\circ\text{C}$. These output voltage levels were selected to approximate the logic threshold voltages of the types of digital logic circuits these comparators are intended to drive.

[†]Full range for TL710M is -55°C to 125°C and for TL710C is 0°C to 70°C .

[‡]The algebraic convention where the most-positive (least-negative) limit is designated as maximum is used in this data sheet for logic levels only, e.g., when 0 V is the maximum, the minimum limit is a more-negative voltage.

4

Voltage Comparators

TYPES TL710M, TL710C DIFFERENTIAL COMPARATORS

switching characteristics, $V_{CC+} = 12\text{ V}$, $V_{CC-} = -6\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TL710M	TL710C	UNIT
		TYP	TYP	
Response time	No load. See Note 5	40	40	ns

NOTE 5: The response time specified is for a 100-mV input step with 5-mV overdrive and is the interval between the input step function and the instant when the output crosses 1.4 V.

TYPICAL CHARACTERISTICS

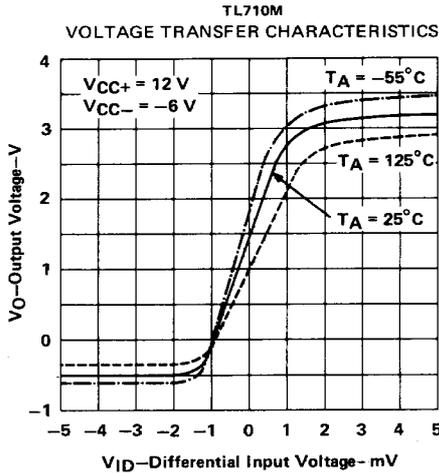


FIGURE 1

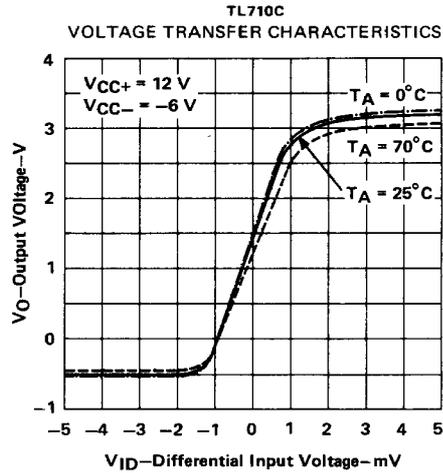


FIGURE 2

4

Voltage Comparators

TYPICAL CHARACTERISTICS

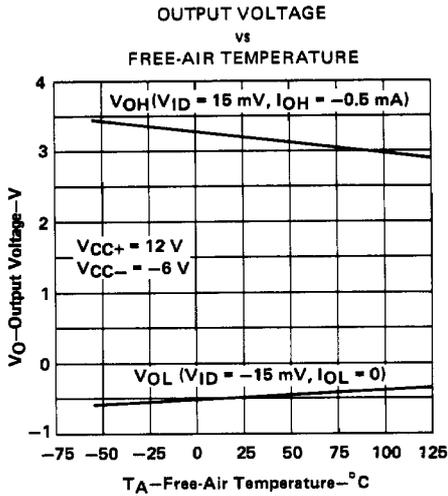


FIGURE 3

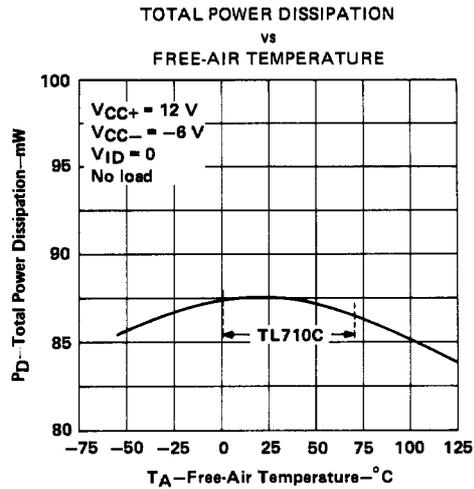


FIGURE 4

OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

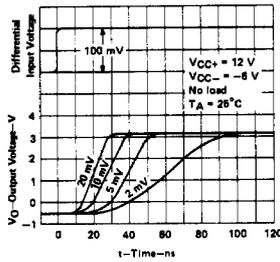


FIGURE 5

OUTPUT RESPONSE FOR VARIOUS INPUT OVERDRIVES

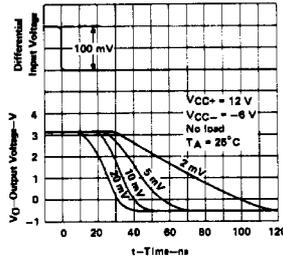


FIGURE 6

COMMON-MODE PULSE RESPONSE
vs
ELAPSED TIME

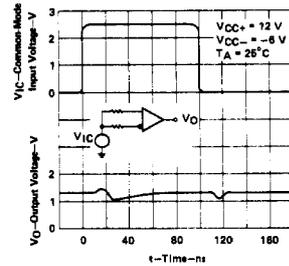


FIGURE 7

4

Voltage Comparators